# SS12P4C

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Vishay General Semiconductor

# High Current Density Surface-Mount Schottky Barrier Rectifier



K Anode 1 Cathode ◄ Anode 2

# LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	2 x 6 A				
V <sub>RRM</sub>	40 V				
I <sub>FSM</sub>	150 A				
E <sub>AS</sub>	20 mJ				
$V_F$ at $I_F = 6 A$	0.40 V				
T <sub>J</sub> max.	125 °C				
Package	SMPC (TO-277A)				
Circuit configuration	Common cathode				

### FEATURES

- Very low profile typical height of 1.1 mm
- · Ideal for automated placement
- · Low forward voltage drop, low power losses
- High efficiency
- · Low thermal impedance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available - Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### TYPICAL APPLICATIONS

For use in low voltage high frequency inverters, freewheeling, DC/DC converters and polarity protection applications.

# MECHANICAL DATA

Case: SMPC (TO-277A)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Base P/NHM3\_X - halogen-free, RoHS-compliant and AEC-Q101 qualified

("\_X" denotes revision code e.g. A, B,....)

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 2 whisker test, HM3 suffix meets JESD 201 class 2 whisker test

<b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER		SYMBOL	SS12P4C	UNIT		
Device marking code			S124C			
Maximum repetitive peak reverse voltage		V <sub>RRM</sub>	40	V		
Maximum average forward rectified current (fig. 1) $^{(1)}$	total device	I <sub>F(AV)</sub>	12	А		
	per diode		6.0			
Maximum average forward rectified current <sup>(2)</sup>	total device	I <sub>F(AV)</sub>	3.5	А		
Peak forward surge current 10 ms single half sine-wave superimposed on rated load per diode		I <sub>FSM</sub>	150	A		
Non-repetitive avalanche energy at $T_J$ = 25 °C, L = 60 mH per diode		E <sub>AS</sub>	20	mJ		
Peak repetitive reverse current at $t_p$ = 2 µs, 1 kHz, at T <sub>J</sub> = 25 °C per diode		I <sub>RRM</sub>	1.0	А		
Operating junction and storage temperature range		T <sub>J,</sub> T <sub>STG</sub>	-55 to +125	°C		

Notes

<sup>(1)</sup> Mounted on 30 mm x 30 mm AI PCB with 50 mm x 25 mm x 100 mm fin heat sink

<sup>(2)</sup> Free air, mounted on recommended copper pad area

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RoHS

COMPLIANT



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<b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25$ °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I <sub>F</sub> = 1 A	T <sub>A</sub> = 25 °C		0.34	-	V
	I <sub>F</sub> = 3 A			0.40	-	
	I <sub>F</sub> = 6 A			0.46	0.52	
	I <sub>F</sub> = 1 A	T <sub>A</sub> = 100 °C		0.24	-	
	I <sub>F</sub> = 3 A			0.31	-	
	I <sub>F</sub> = 6 A			0.40	0.45	
Reverse current per diode	Rated V <sub>R</sub>	T <sub>A</sub> = 25 °C T <sub>A</sub> = 100 °C	I <sub>R</sub> <sup>(2)</sup>	129	500	μΑ
	naleu VR		'R '-'	11.9	25	mA
Typical junction capacitance per diode	4.0 V, 1 MHz		CJ	400	-	pF

#### Notes

<sup>(1)</sup> Pulse test: 300 µs pulse width, 1 % duty cycle

<sup>(2)</sup> Pulse test: Pulse width  $\leq$  40 ms

<b>THERMAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER	RAMETER SYMBOL SS12P4C		UNIT		
Typical thermal resistance	R <sub>0JA</sub> <sup>(1)</sup>	100	°C/W		
	R <sub>0JM</sub> <sup>(2)</sup>	3			

#### Notes

<sup>(1)</sup> Free air, mounted on recommended copper pad area. Thermal resistance  $R_{\theta JA}$  - junction to ambient

 $^{(2)}$  Mounted on 30 mm x 30 mm Al PCB with 50 mm x 25 mm x 100 mm fin heat sink. Thermal resistance R<sub>0JM</sub> - junction to mount

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
SS12P4C-M3/86A	0.10	86A	1500	7" diameter plastic tape and reel		
SS12P4C-M3/87A	0.10	87A	6500	13" diameter plastic tape and reel		
SS12P4CHM3_A/H <sup>(1)</sup>	0.10	Н	1500	7" diameter plastic tape and reel		
SS12P4CHM3_A/I (1)	0.10	I	6500	13" diameter plastic tape and reel		

#### Note

(1) AEC-Q101 qualified

# **RATINGS AND CHARACTERISTICS CURVES** (T<sub>A</sub> = 25 °C unless otherwise noted)

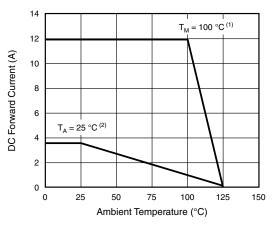


Fig. 1 - Maximum Forward Current Derating Curve

#### Notes

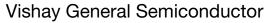
- Mounted on 30 mm x 30 mm Al PCB with 50 mm x 25 mm x 100 mm fin heat sink, T<sub>M</sub> measured at the terminal of cathode band ( $R_{\theta JM} = 3 \text{ °C/W}$ )
- Free air, mounted on recommended copper pad area ( $R_{\theta JA}$  = 100 °C/W)

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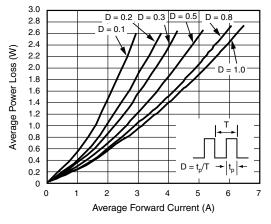


Fig. 2 - Forward Power Loss Characteristics Per Diode

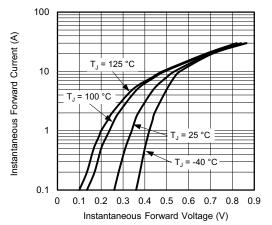


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

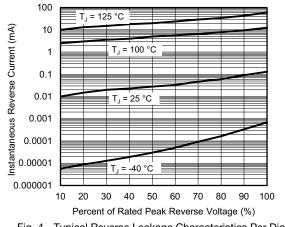


Fig. 4 - Typical Reverse Leakage Characteristics Per Diode

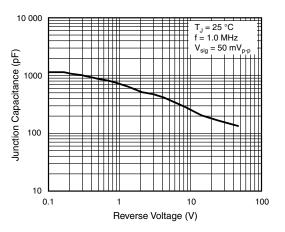


Fig. 5 - Typical Junction Capacitance Per Diode

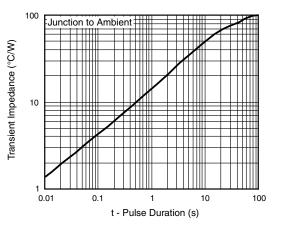


Fig. 6 - Typical Transient Thermal Impedance Per Diode

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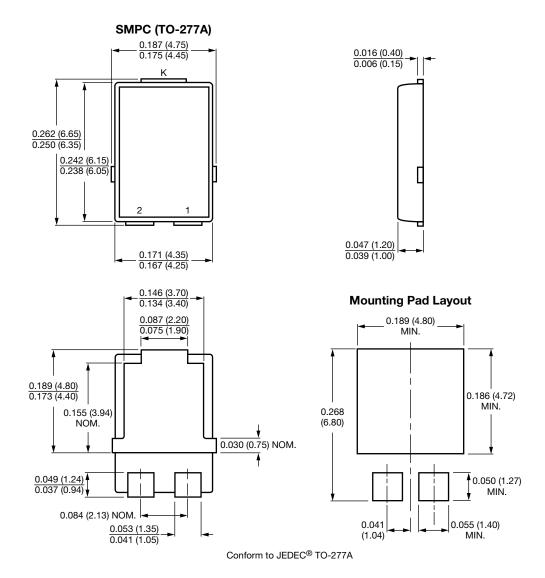
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### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)





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